

长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech, Co., Ltd.

DATA SHEET

DPS-266-Q/2~5mJ

SPECIFICATIONS

HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE Q-SWITCHED LASER

High energy diode pumped all solid state Q-switched laser at 266nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIBS, LIF, PIV, ICP-MS,LCD repair, scientific research, laser processing, and so on.



Wavelength (nm)	266±1		
Operating mode	Q-switched: EOM (Electro-optic modulation)		
Single pulse energy (mJ)	2	5	
Pulse duration (ns)	<10		
Rep. rate (Hz)	1~100 (adjustable)		
Energy stability	<5%, <4%		
Beam divergence, full angle (mrad)	<3		
Beam diameter (mm)	~2	~2.5	
Warm-up time (minutes)	<15		
Beam height from base plate (mm)	55		
Cooled method	Water Cooled		
Operating temperature (°C)	15~30		
Power supply (220VAC)	PSU-DPS-Q-I		
Expected lifetime(pulses)	109		
Warranty period	1 year		





